



BUK7Y7R0-40H

N-channel 40 V, 7.0 mΩ standard level MOSFET in LPAK56

10 January 2025

Product data sheet

1. General description

Automotive qualified N-channel MOSFET using the latest Trench 9 low ohmic superjunction technology, housed in a robust LPAK56 package. This product has been fully designed and qualified to meet AEC-Q101 requirements delivering high performance and endurance.

2. Features and benefits

- Fully automotive qualified to AEC-Q101:
 - 175 °C rating suitable for thermally demanding environments
- Trench 9 Superjunction technology:
 - Reduced cell pitch enables enhanced power density and efficiency with lower R_{DSon} in same footprint
 - Improved SOA and avalanche capability compared to standard TrenchMOS
 - Tight $V_{GS(th)}$ limits enable easy paralleling of MOSFETs
- LPAK Gull Wing leads:
 - High Board Level Reliability absorbing mechanical stress during thermal cycling, unlike traditional QFN packages
 - Visual (AOI) soldering inspection, no need for expensive x-ray equipment
 - Easy solder wetting for good mechanical solder joint
- LPAK copper clip technology:
 - Improved reliability, with reduced R_{th} and R_{DSon}
 - Increases maximum current capability and improved current spreading

3. Applications

- 12 V automotive systems
- Motors, lamps and solenoid control
- Start-Stop micro-hybrid applications
- Transmission control
- Ultra high performance power switching

4. Quick reference data

Table 1. Quick reference data

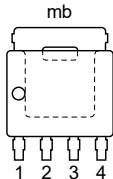
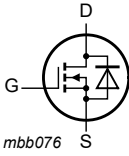
| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|-------------------------------|----------------------------------|---|-----|-----|-----|-----|------|
| V_{DS} | drain-source voltage | $25\text{ °C} \leq T_j \leq 175\text{ °C}$ | | - | - | 40 | V |
| I_D | drain current | $V_{GS} = 10\text{ V}$; $T_{mb} = 25\text{ °C}$; Fig. 2 | [1] | - | - | 68 | A |
| P_{tot} | total power dissipation | $T_{mb} = 25\text{ °C}$; Fig. 1 | | - | - | 64 | W |
| Static characteristics | | | | | | | |
| R_{DSon} | drain-source on-state resistance | $V_{GS} = 10\text{ V}$; $I_D = 15\text{ A}$; $T_j = 25\text{ °C}$; Fig. 11 | | 4 | 5.7 | 7 | mΩ |

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------------|-------------------|---|-----|------|-----|------|
| Dynamic characteristics | | | | | | |
| Q_{GD} | gate-drain charge | $I_D = 15\text{ A}$; $V_{DS} = 32\text{ V}$; $V_{GS} = 10\text{ V}$; Fig. 13 ; Fig. 14 | - | 3.7 | 7.4 | nC |
| Source-drain diode | | | | | | |
| Q_r | recovered charge | $I_S = 15\text{ A}$; $di_S/dt = -100\text{ A/}\mu\text{s}$; $V_{GS} = 0\text{ V}$; $V_{DS} = 20\text{ V}$; Fig. 17 | - | 10 | - | nC |
| S | softness factor | $I_S = 15\text{ A}$; $di_S/dt = -100\text{ A/}\mu\text{s}$; $V_{GS} = 0\text{ V}$; $V_{DS} = 20\text{ V}$; $T_j = 25\text{ }^\circ\text{C}$; Fig. 17 | - | 0.78 | - | |

[1] 68A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-----------------------------------|---|--|
| 1 | S | source |  LFPAK56; Power-SO8 (SOT669) |  mbb076 |
| 2 | S | source | | |
| 3 | S | source | | |
| 4 | G | gate | | |
| mb | D | mounting base; connected to drain | | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|------------------------------|--------------------|--|------------------------|
| | Name | Description | Version |
| BUK7Y7R0-40H | LFPAK56; Power-SO8 | plastic, single-ended surface-mounted package; 4 terminals | SOT669 |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|--------------|--------------|
| BUK7Y7R0-40H | 77H040 |

8. Limiting values

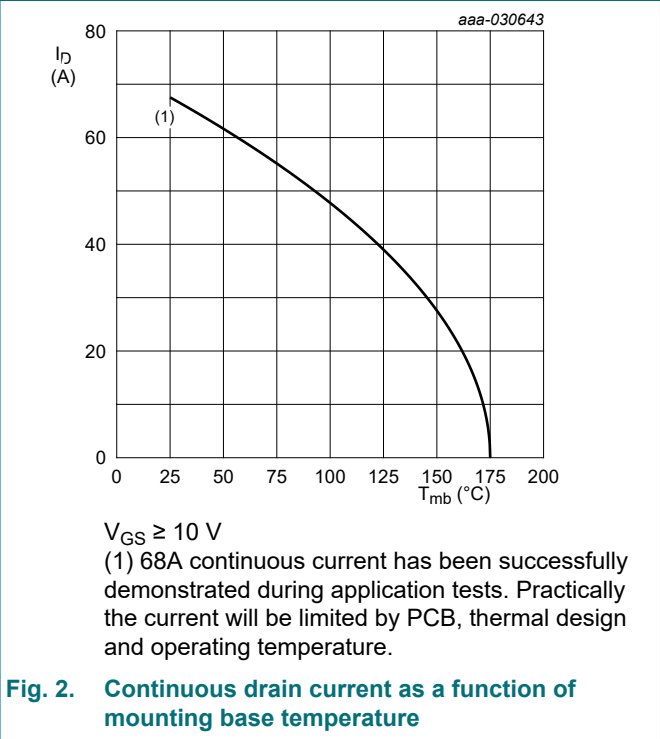
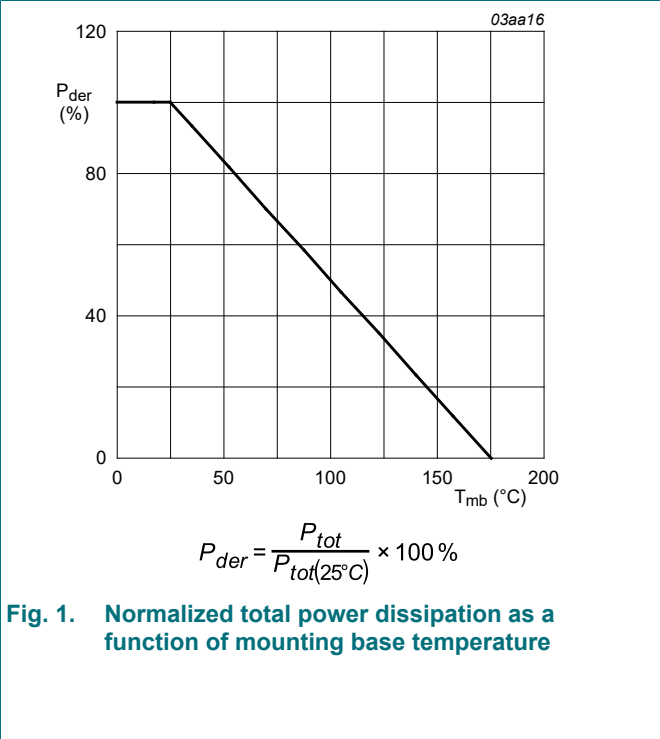
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). $T_j = 25\text{ }^\circ\text{C}$ unless otherwise stated.

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|---|-----|-----|-----|------|
| V _{DS} | drain-source voltage | 25 °C ≤ T _j ≤ 175 °C | | - | 40 | V |
| V _{GS} | gate-source voltage | | [1] | -20 | 20 | V |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; Fig. 1 | | - | 64 | W |

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|----------------------|--|---|---------|-----|------|------|
| I _D | drain current | V _{GS} = 10 V; T _{mb} = 25 °C; Fig. 2 | [2] | - | 68 | A |
| | | V _{GS} = 10 V; T _{mb} = 100 °C; Fig. 2 | | - | 48 | A |
| I _{DM} | peak drain current | pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C; Fig. 3 | | - | 272 | A |
| T _{stg} | storage temperature | | | -55 | 175 | °C |
| T _j | junction temperature | | | -55 | 175 | °C |
| Source-drain diode | | | | | | |
| I _S | source current | T _{mb} = 25 °C | | - | 64 | A |
| I _{SM} | peak source current | pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C | | - | 272 | A |
| Avalanche ruggedness | | | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | I _D = 68 A; V _{sup} ≤ 40 V; R _{GS} = 50 Ω; V _{GS} = 10 V; T _{j(init)} = 25 °C; unclamped; Fig. 4 | [3] [4] | - | 19.9 | mJ |

- [1] Refer to application note AN90001 for further information.
- [2] 68A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.
- [3] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.
- [4] Refer to application note AN10273 for further information.



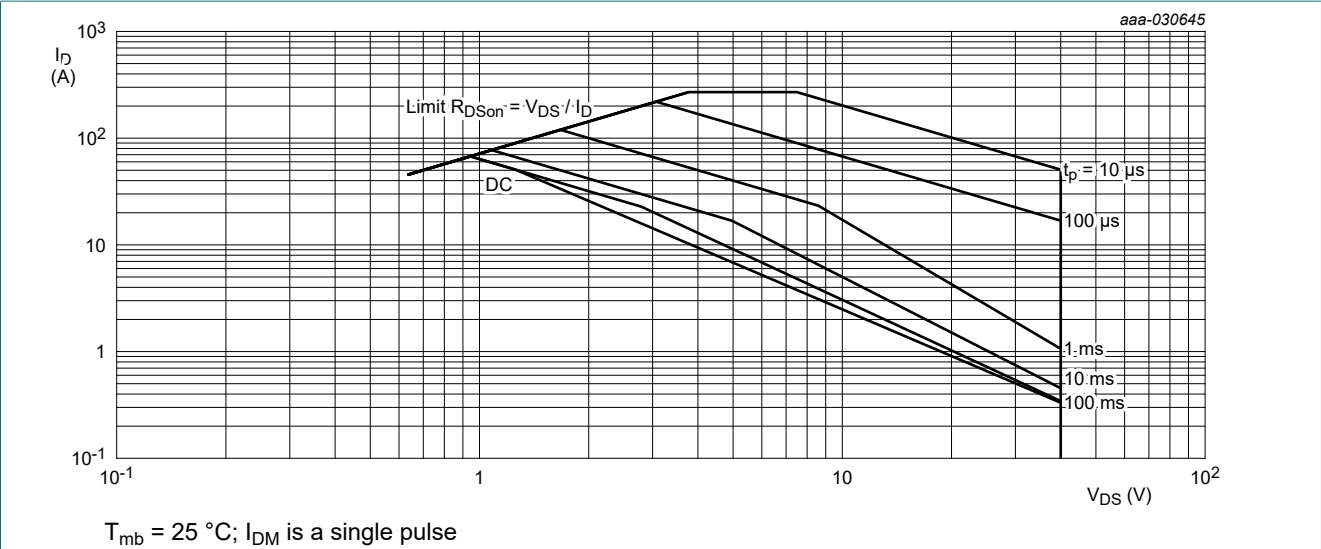


Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

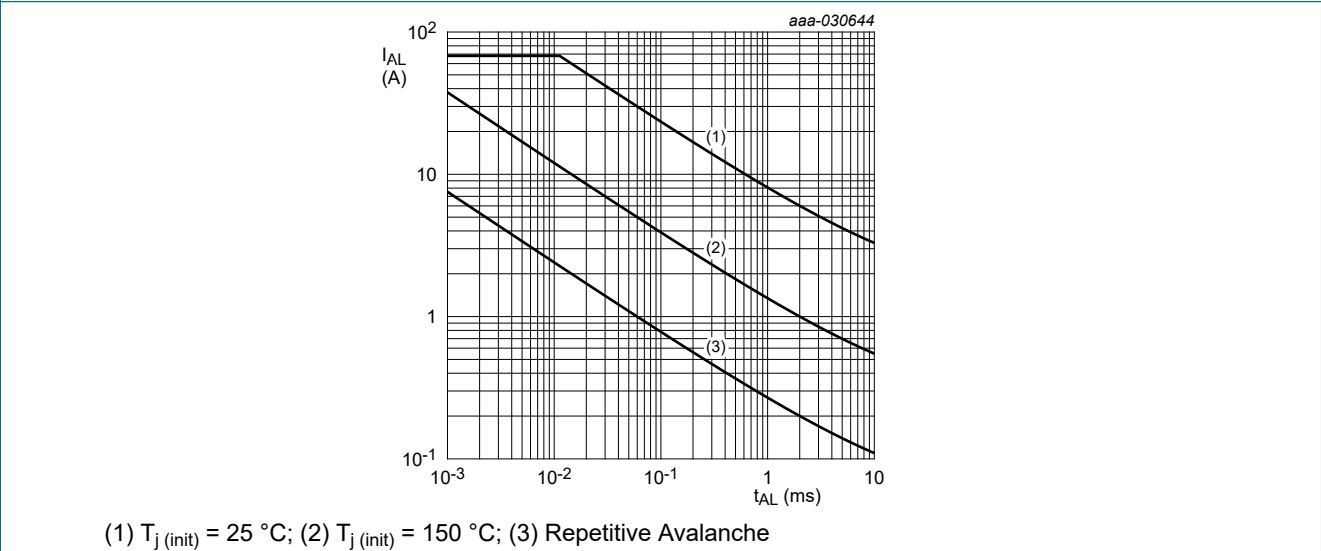


Fig. 4. Avalanche rating; avalanche current as a function of avalanche time

9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------|---|------------|-----|------|------|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | Fig. 5 | - | 2.17 | 2.35 | K/W |

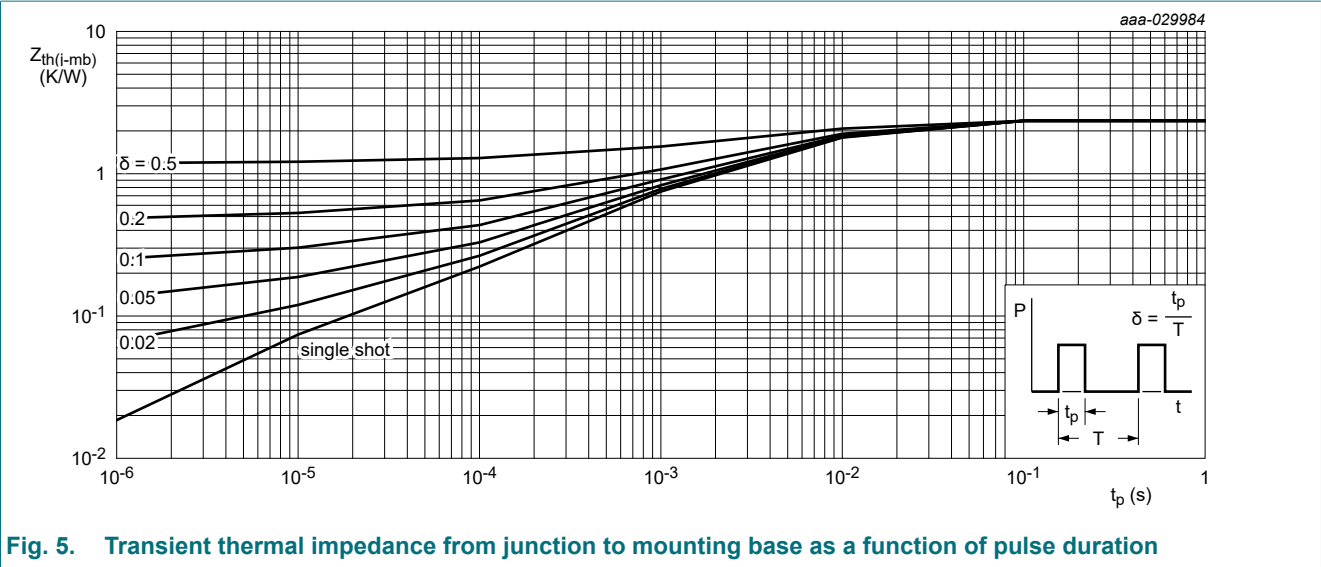


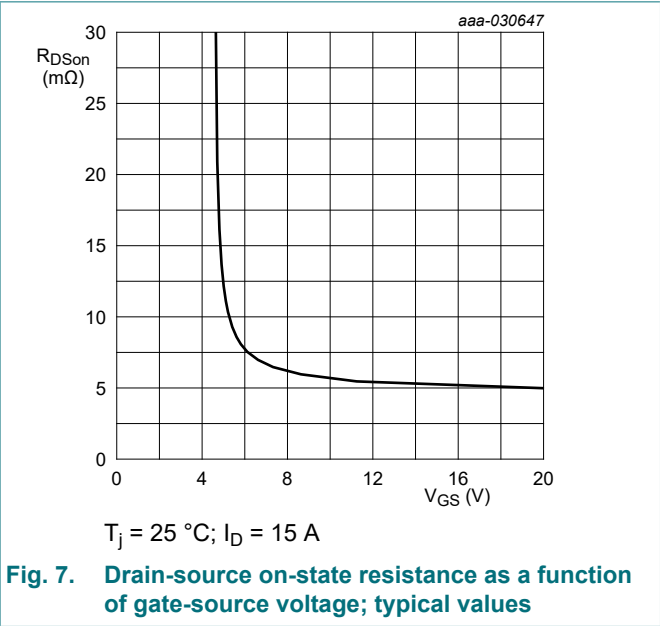
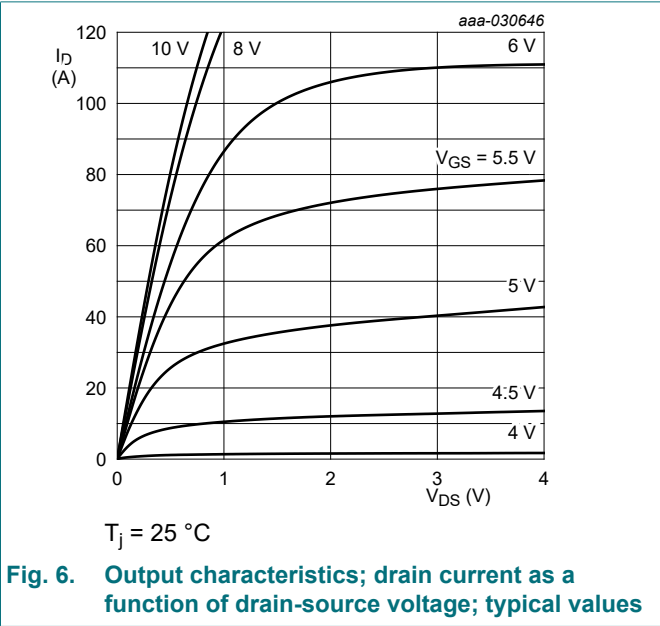
Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------------|----------------------------------|--|-----|------|------|------|
| Static characteristics | | | | | | |
| V _{(BR)DSS} | drain-source breakdown voltage | I _D = 250 μA; V _{GS} = 0 V; T _J = 25 °C | 40 | 43 | - | V |
| | | I _D = 250 μA; V _{GS} = 0 V; T _J = -40 °C | - | 40.5 | - | V |
| | | I _D = 250 μA; V _{GS} = 0 V; T _J = -55 °C | 36 | 40 | - | V |
| V _{GS(th)} | gate-source threshold voltage | I _D = 1 mA; V _{DS} =V _{GS} ; T _J = 25 °C; Fig. 9 ; Fig. 10 | 2.4 | 3 | 3.6 | V |
| | | I _D = 1 mA; V _{DS} =V _{GS} ; T _J = -55 °C; Fig. 10 | - | - | 4.3 | V |
| | | I _D = 1 mA; V _{DS} =V _{GS} ; T _J = 175 °C; Fig. 10 | 1 | - | - | V |
| I _{DSS} | drain leakage current | V _{DS} = 40 V; V _{GS} = 0 V; T _J = 25 °C | - | 0.01 | 1 | μA |
| | | V _{DS} = 16 V; V _{GS} = 0 V; T _J = 125 °C | - | 0.51 | 10 | μA |
| | | V _{DS} = 40 V; V _{GS} = 0 V; T _J = 175 °C | - | 39 | 500 | μA |
| I _{GSS} | gate leakage current | V _{GS} = 20 V; V _{DS} = 0 V; T _J = 25 °C | - | 2 | 100 | nA |
| | | V _{GS} = -20 V; V _{DS} = 0 V; T _J = 25 °C | - | 2 | 100 | nA |
| R _{DSon} | drain-source on-state resistance | V _{GS} = 10 V; I _D = 15 A; T _J = 25 °C; Fig. 11 | 4 | 5.7 | 7 | mΩ |
| | | V _{GS} = 10 V; I _D = 15 A; T _J = 105 °C; Fig. 12 | 5.5 | 8 | 10.5 | mΩ |
| | | V _{GS} = 10 V; I _D = 15 A; T _J = 125 °C; Fig. 12 | 6 | 8.7 | 11.3 | mΩ |
| | | V _{GS} = 10 V; I _D = 15 A; T _J = 175 °C; Fig. 12 | 7.3 | 10.7 | 13.6 | mΩ |
| R _G | gate resistance | f = 1 MHz; T _J = 25 °C | 0.3 | 0.7 | 1.8 | Ω |
| Dynamic characteristics | | | | | | |
| Q _{G(tot)} | total gate charge | I _D = 15 A; V _{DS} = 32 V; V _{GS} = 10 V; Fig. 13 ; Fig. 14 | - | 18 | 26 | nC |
| Q _{GS} | gate-source charge | | - | 5.4 | 8.1 | nC |
| Q _{GD} | gate-drain charge | | - | 3.7 | 7.4 | nC |

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|---------------------|------------------------------|---|--|-----|------|------|------|
| C _{iss} | input capacitance | V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz; T _j = 25 °C; Fig. 15 | | - | 1164 | 1630 | pF |
| C _{oss} | output capacitance | | | - | 408 | 571 | pF |
| C _{rss} | reverse transfer capacitance | | | - | 63 | 139 | pF |
| t _{d(on)} | turn-on delay time | V _{DS} = 30 V; R _L = 2 Ω; V _{GS} = 10 V; R _{G(ext)} = 5 Ω | | - | 5.8 | - | ns |
| t _r | rise time | | | - | 4 | - | ns |
| t _{d(off)} | turn-off delay time | | | - | 10.5 | - | ns |
| t _f | fall time | | | - | 4.4 | - | ns |
| Source-drain diode | | | | | | | |
| V _{SD} | source-drain voltage | I _S = 15 A; V _{GS} = 0 V; T _j = 25 °C; Fig. 16 | | - | 0.83 | 1 | V |
| t _{rr} | reverse recovery time | I _S = 15 A; dI _S /dt = -100 A/μs; V _{GS} = 0 V; V _{DS} = 20 V; Fig. 17 | | - | 20 | - | ns |
| Q _r | recovered charge | | | - | 10 | - | nC |
| S | softness factor | I _S = 15 A; dI _S /dt = -100 A/μs; V _{GS} = 0 V; V _{DS} = 20 V; T _j = 25 °C; Fig. 17 | | - | 0.78 | - | |
| | | I _S = 15 A; dI _S /dt = -500 A/μs; V _{GS} = 0 V; V _{DS} = 20 V; T _j = 25 °C; Fig. 17 | | - | 0.66 | - | |



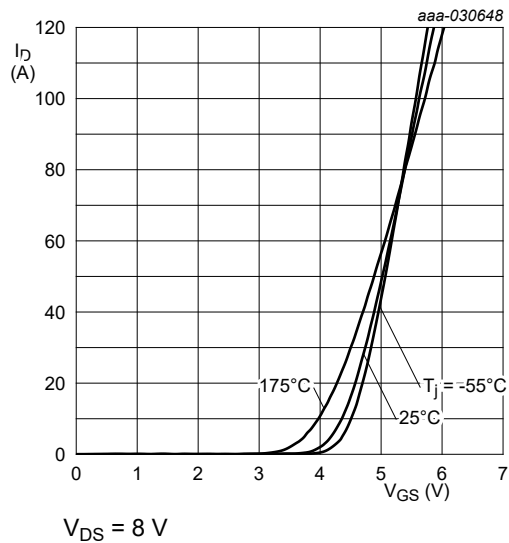


Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

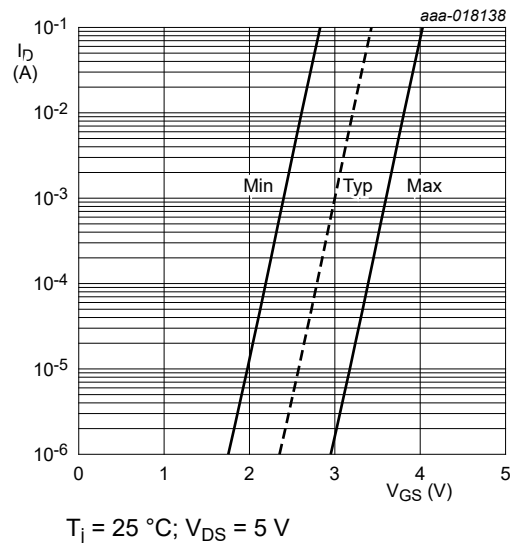


Fig. 9. Sub-threshold drain current as a function of gate-source voltage

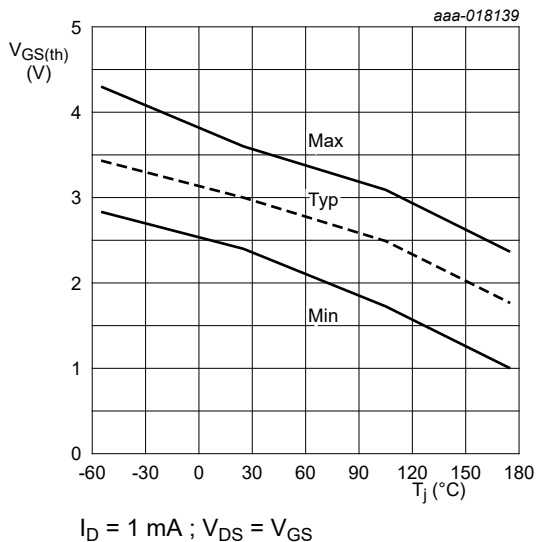


Fig. 10. Gate-source threshold voltage as a function of junction temperature

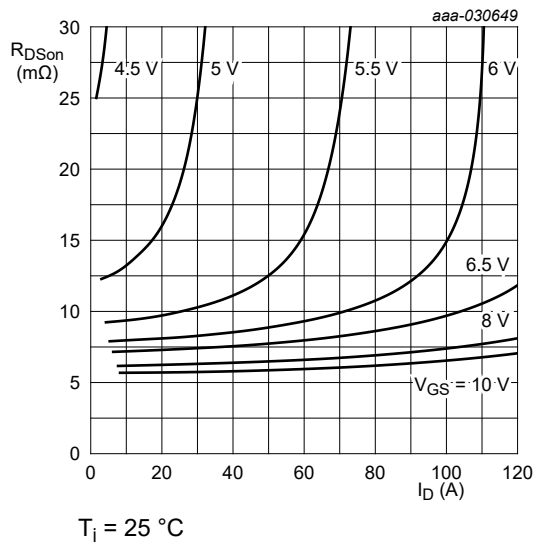


Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

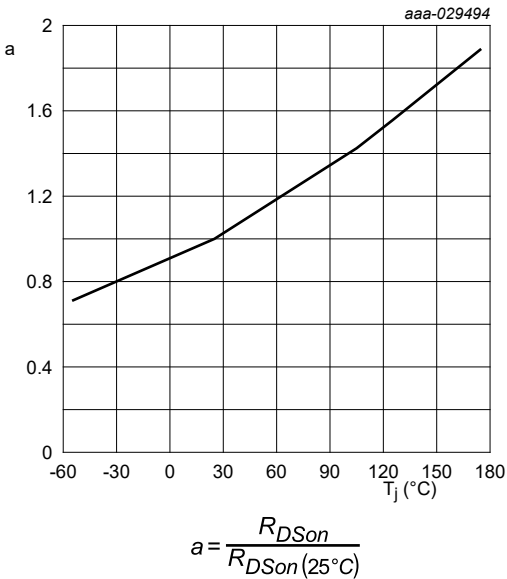


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

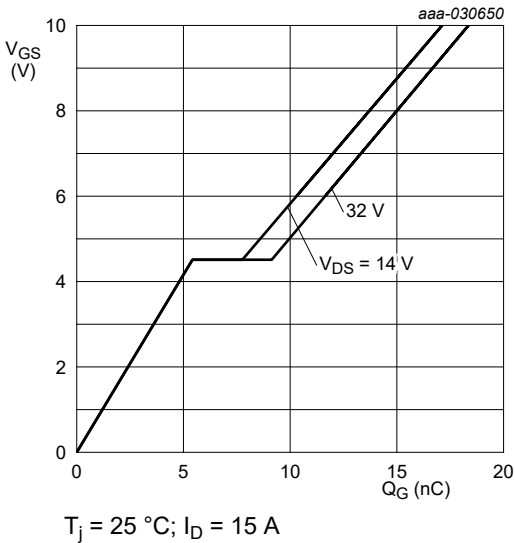


Fig. 13. Gate-source voltage as a function of gate charge; typical values



Fig. 14. Gate charge waveform definitions

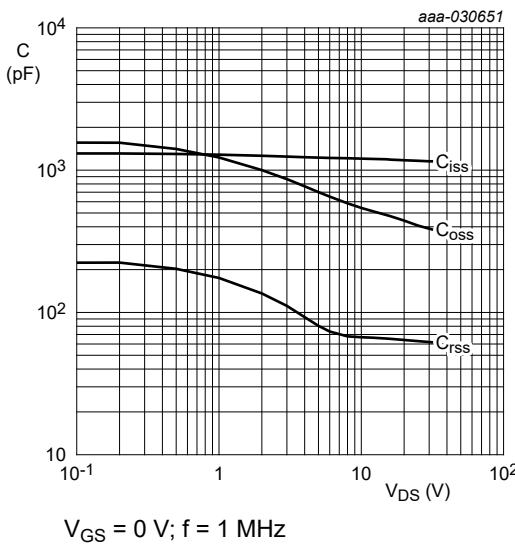


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

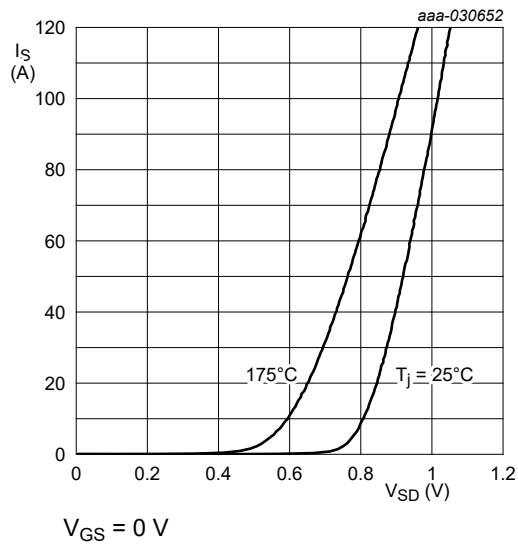


Fig. 16. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

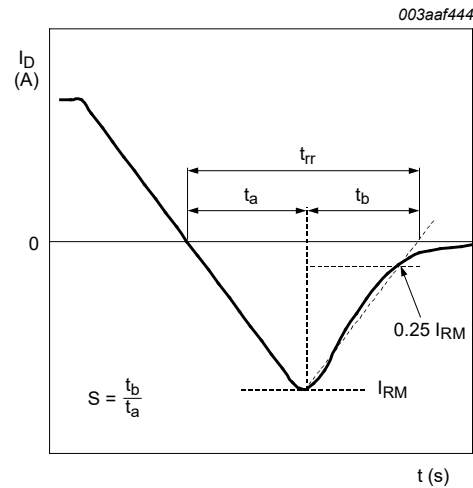


Fig. 17. Reverse recovery timing definition

11. Package outline

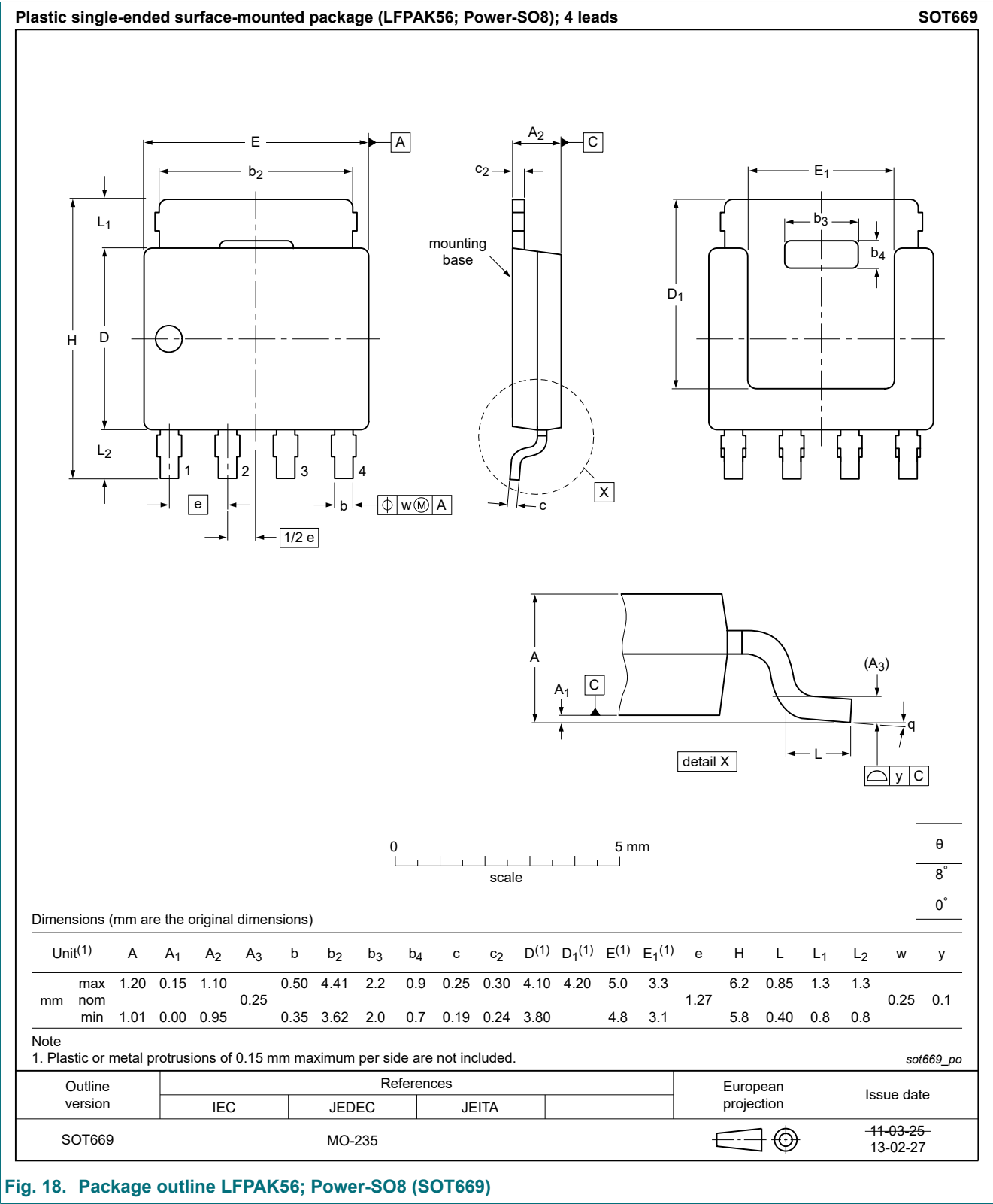


Fig. 18. Package outline LPAK56; Power-SO8 (SOT669)

12. Soldering

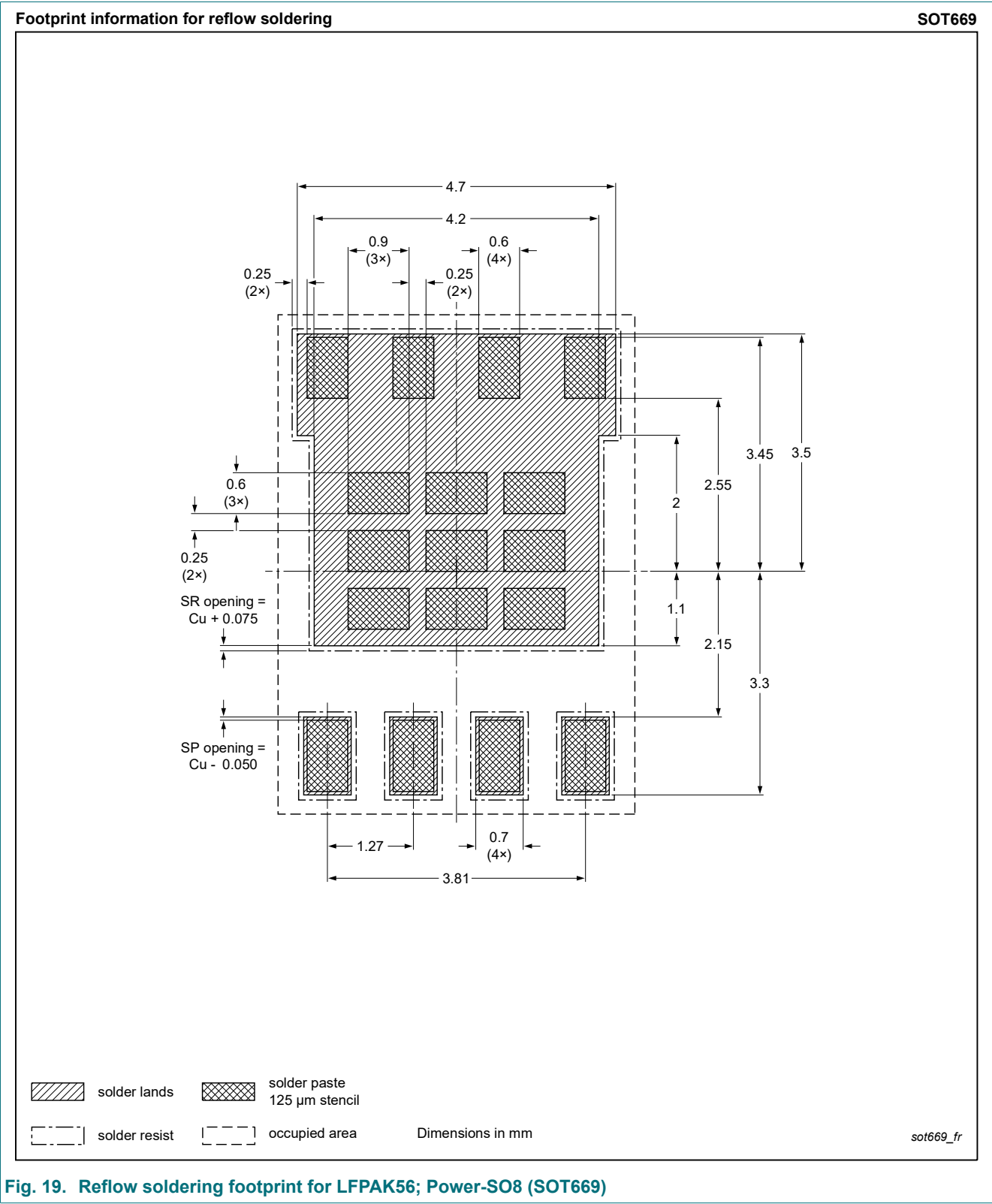
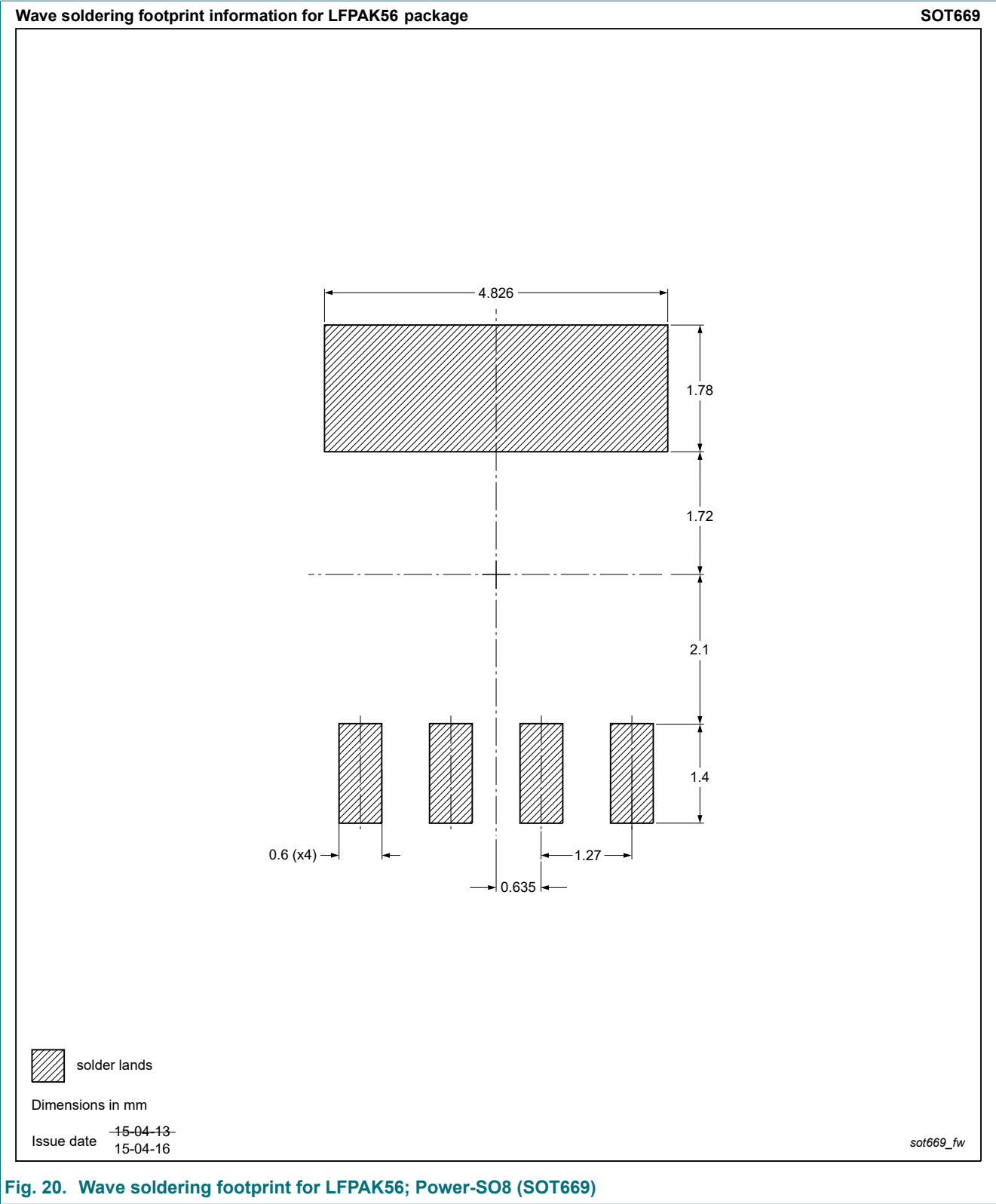


Fig. 19. Reflow soldering footprint for LPAK56; Power-SO8 (SOT669)



13. Legal information

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|--------------------------------|--------------------|---|
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Date of release: 10 January 2025

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